

TIP32C

Power transistor

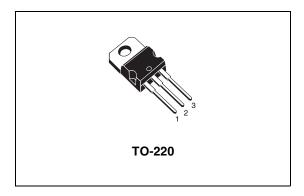
Applications

■ Linear and swithing industrial equipment

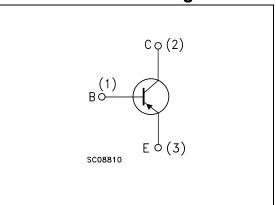
Description

The TIP32C is a silicon Epitaxial-base PNP power transistor in Jedec TO-220 plastic package. It is intented for use in medium power linear and switching applications.

The complementary NPN type is TIP31C.



Internal schematic diagram



Order codes

Part number	Marking	Package	Packing	
TIP32C	TIP32C	TO-220	Tube	

November 2006 Rev 2 1/8

1 Absolute maximum ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	-100	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	-100	V
V _{EBO}	Emitte-base voltage ($I_C = 0$)	-5	V
I _C	Collector current	-3	Α
I _{CM}	Collector peak current (t _P < 5ms)	-5	Α
Ι _Β	Base current	-1	Α
D	Total dissipation at T _{case} = 25°C	40	W
P _{TOT}	T _{amb} = 25°C	2	W
T _{stg}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C; unless otherwise specified)$

Table 2. Electrical characteristics

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CEO}	Collector cut-off current (I _B = 0)	V _{CB} =-60V			-0.3	mA
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CB} =-100V			-0.2	mA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} =-5V			-1	mA
V _{CEO(sus}	Collector-emitter sustaining voltage (I _B = 0)	I _C = -30mA	-100			V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_C = -3A$ $I_B = 375mA$			-1.2	V
V _{BE(on)} ⁽¹⁾	Base-emitter voltage	$I_C = -3A$ $V_{CE} = -4V$			-1.8	٧
h _{FE} ⁽¹⁾	DC current gain	$I_C = -1A$ $V_{CE} = -4V$ $I_C = -3A$ $V_{CE} = -4V$	25 10		50	

^{1.} Pulsed duration = 300 ms, duty cycle ≥1.5%.

577

Electrical characteristics TIP32C

2.1 Typical characteristic

Figure 1. Safe operating area

Ic (A)

lc MAX PULSED PULSE OPERATION*

100 µs

100 D.C. OPERATION

100 µs

Figure 2. Derating Curves

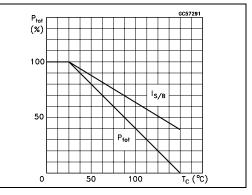


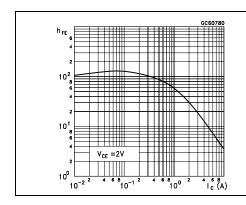
Figure 3. DC current gain

10⁻¹

* FOR SINGLE NON REPETITIVE PULSE

> 8 10¹

Figure 4. Collector-emitter saturation voltage



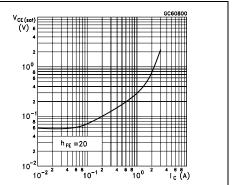
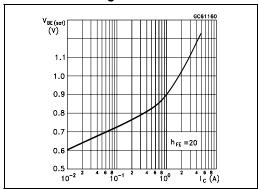


Figure 5. Base-emitter saturation voltage



4/8

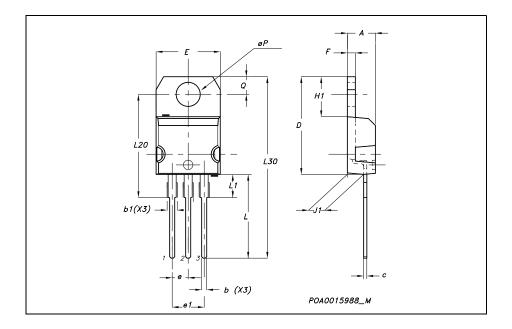
3 Package Mechanical Data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

577

TO-220 MECHANICAL DA

DIM.	mm.			inch		
DIW.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
Α	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.15		1.70	0.045		0.066
С	0.49		0.70	0.019		0.027
D	15.25		15.75	0.60		0.620
E	10		10.40	0.393		0.409
е	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
F	1.23		1.32	0.048		0.052
H1	6.20		6.60	0.244		0.256
J1	2.40		2.72	0.094		0.107
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L20		16.40			0.645	
L30		28.90			1.137	
øΡ	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116



6/8

TIP32C Revision History

4 Revision History

Table 3. Revision history

Date	Revision	Changes
10-Oct-1999	1	Initial Release
15-Nov-2006	2	The document has been reformatted

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION). OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

 ${\rm ST}$ and the ${\rm ST}$ logo are trademarks or registered trademarks of ${\rm ST}$ in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2006 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

4

8/8